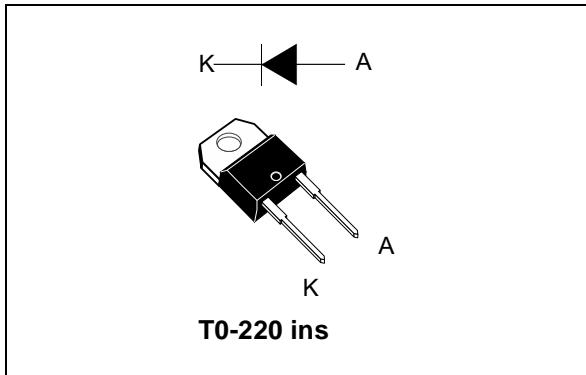




600V schottky diode

CI10H60C3



**Table 1. Device summary**

Symbol	Value
$I_{F(AV)}$	10 A
$V_{RRM}$	600 V
$t_{rr}$ (typ)	8 ns
$I_{RM}$ (typ)	2 A
$V_F$ (typ)	3.2 V
$I_{FRM}$	60 A
$T_j$ (max)	175 °C

## Features

- High voltage rectifier
- Very low switching losses
- Insulated device with internal ceramic
- Static and dynamic equilibrium of internal diodes are warranted by design

## 1 Characteristics

**Table 2. Absolute ratings (limiting values at  $T_j = 25^\circ\text{C}$ , unless otherwise specified)**

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive peak reverse voltage	$T_j$ from 25 to 150 °C	600	V
		$T_j = -40^\circ\text{C}$	550	
$I_{F(RMS)}$	Forward rms current		16	A
$I_{F(AV)}$	Average forward current, $\delta = 0.5$ , square wave		10	A
$I_{FSM}$	Surge non repetitive forward current		70	A
$I_{FRM}$	Repetitive peak forward current		50	A
$T_{stg}$	Storage temperature range		-65 to +175	°C
$T_j$	Operating junction temperature range		-40 to +175	°C

**Table 3. Thermal parameters**

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case	2.9	°C/W

**Table 4. Static electrical characteristics**

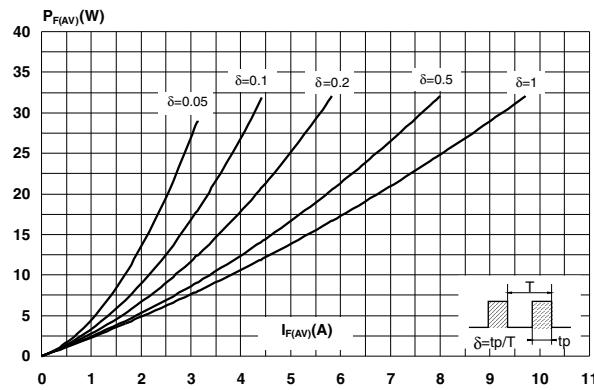
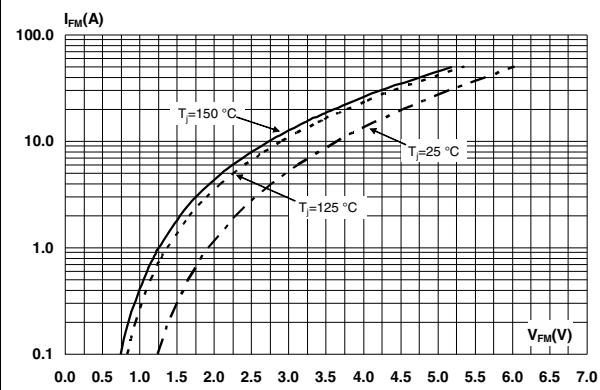
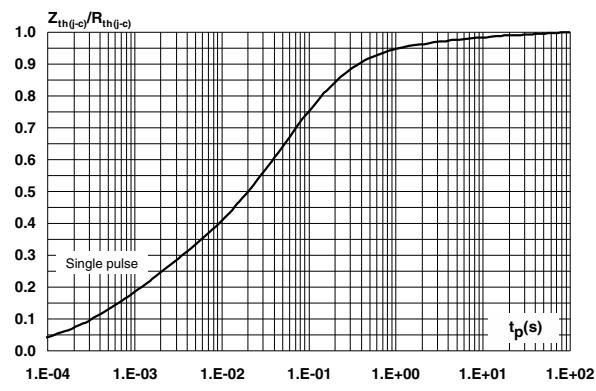
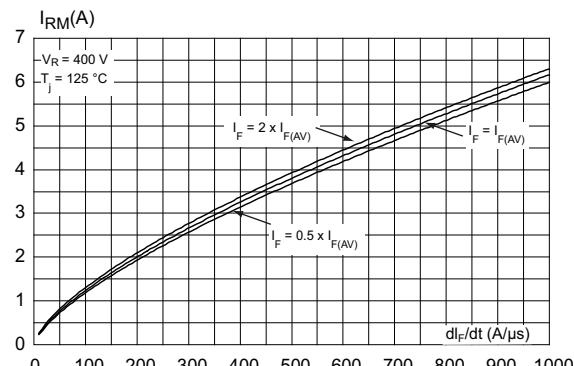
Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$	-		6	μA
		$T_j = 125^\circ\text{C}$		-	20	200	
$V_F^{(2)}$	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 10 \text{ A}$	-	3.2		V
		$T_j = 150^\circ\text{C}$		-	2.0		

1. Pulse test:  $t_p = 5 \text{ ms}$ ,  $\delta < 2\%$ 

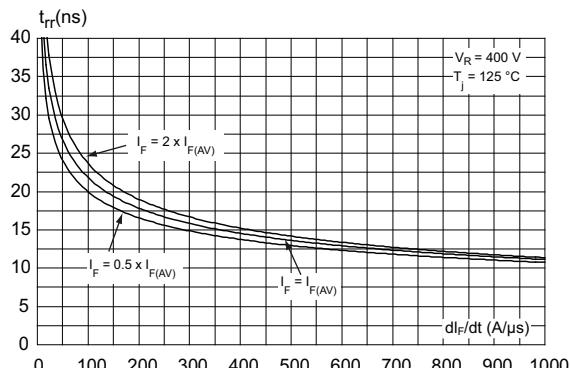
2. Pulse test:  $t_p = 380 \mu\text{s}$ ,  $\delta < 2\%$

**Table 5. Dynamic characteristics**

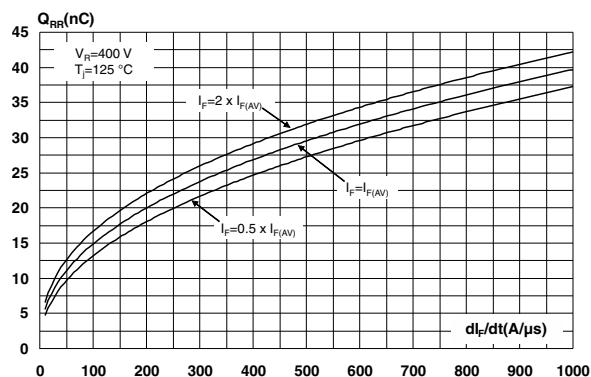
Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$t_{rr}$	Reverse recovery time	$T_j = 25^\circ\text{C}$	$I_F = 1 \text{ A}, V_R = 30 \text{ V},$ $dI_F/dt = -50 \text{ A}/\mu\text{s}$	-	8		ns
			$I_F = 10 \text{ A}, V_R = 400 \text{ V},$ $dI_F/dt = -200 \text{ A}/\mu\text{s}$	-	12		
$I_{RM}$	Reverse recovery current	$T_j = 125^\circ\text{C}$	$I_F = 10 \text{ A}, V_R = 400 \text{ V},$ $dI_F/dt = -200 \text{ A}/\mu\text{s}$	-	2	2.6	A
S	Softness factor			-	0.9		-
$Q_{RR}$	Reverse recovery charge	$T_j = 25^\circ\text{C}$	$I_F = 10 \text{ A}, V_R = 400 \text{ V},$ $dI_F/dt = -200 \text{ A}/\mu\text{s}$		5		nC
		$T_j = 125^\circ\text{C}$		-	22		

**Figure 1. Average forward power dissipation versus average forward current**

**Figure 2. Forward voltage drop versus forward current (typical values)**

**Figure 3. Relative variation of thermal impedance, junction to case, versus pulse duration**

**Figure 4. Peak reverse recovery current versus  $dI_F/dt$  (typical values)**


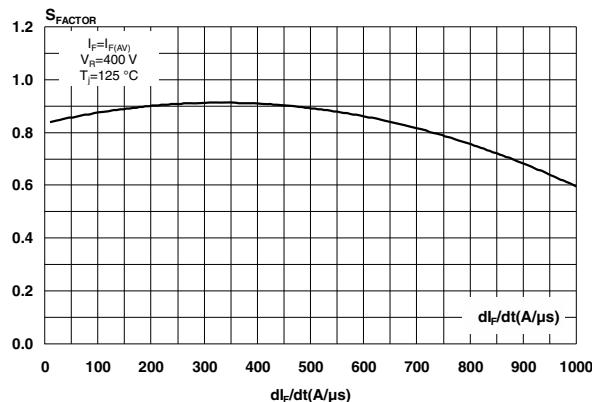
**Figure 5. Reverse recovery time versus  $dl_F/dt$  (typical values)**



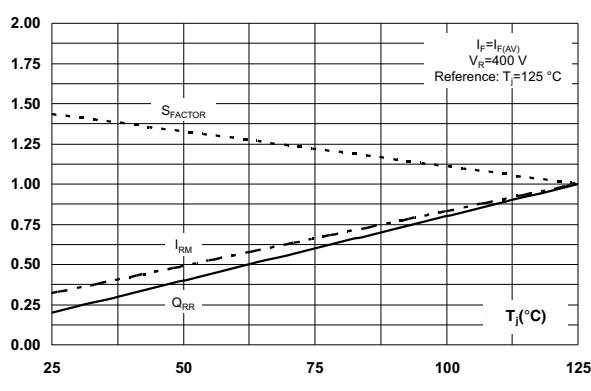
**Figure 6. Reverse recovery charges versus  $dl_F/dt$  (typical values)**



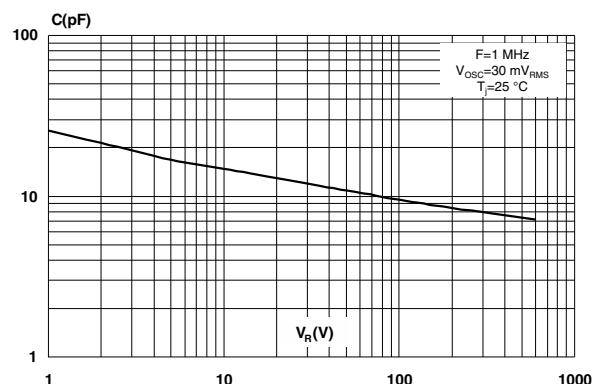
**Figure 7. Reverse recovery softness factor versus  $dl_F/dt$  (typical values)**



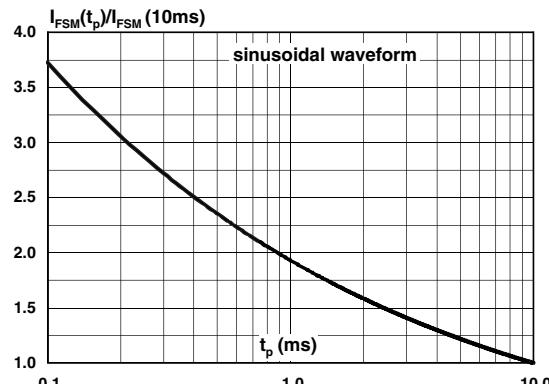
**Figure 8. Relative variations of dynamic parameters versus junction temperature**



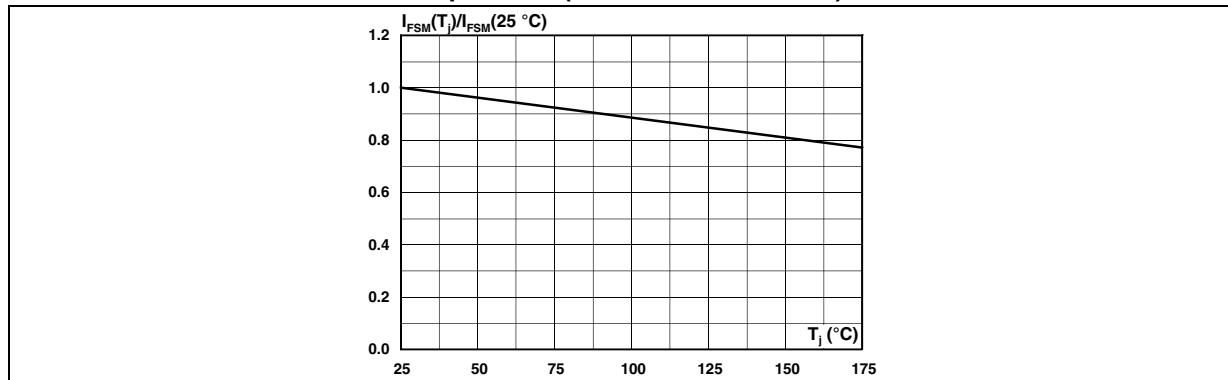
**Figure 9. Junction capacitance versus reverse voltage applied (typical values)**



**Figure 10. Relative variation of non-repetitive peak surge forward current versus pulse duration**

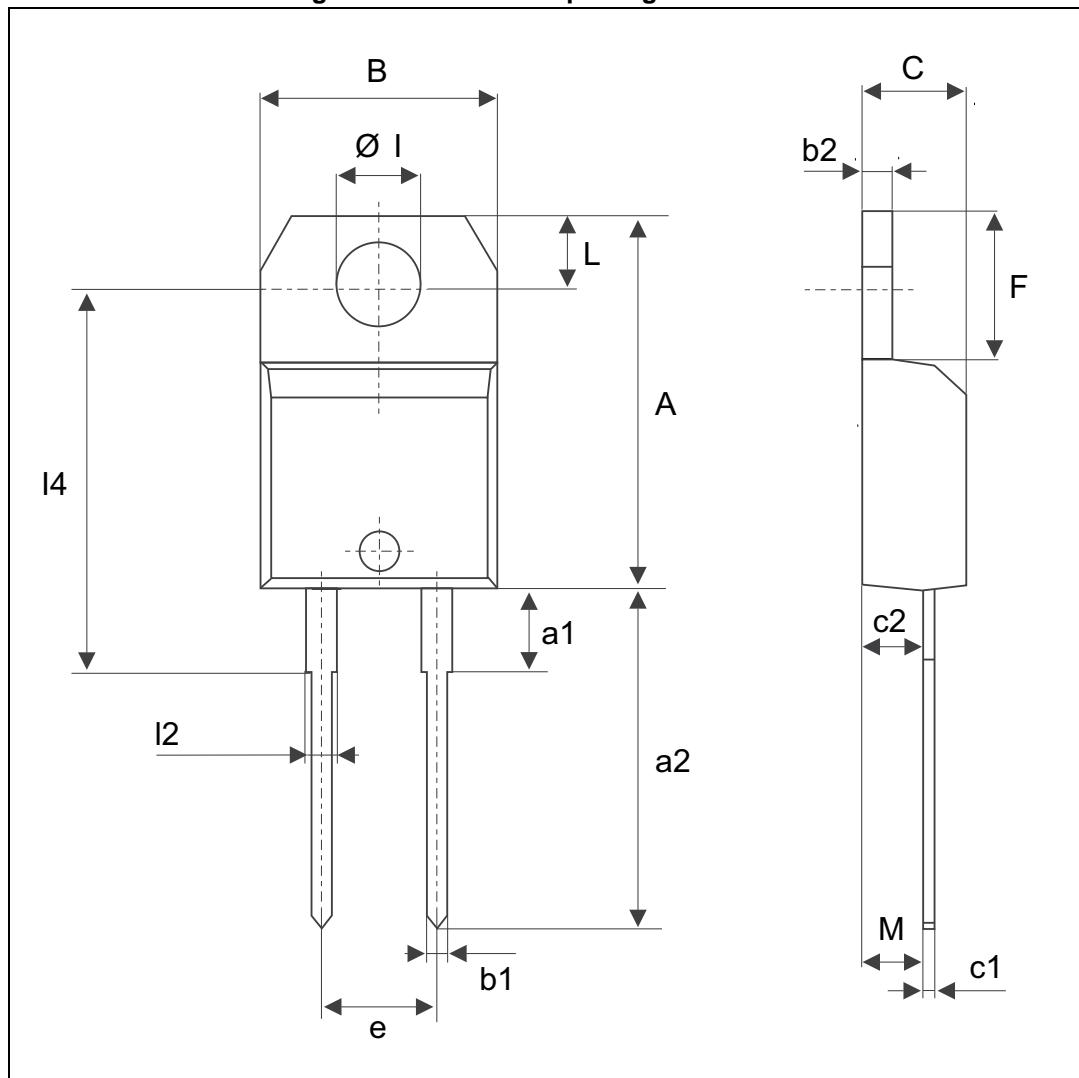


**Figure 11. Relative variation of non-repetitive peak surge forward current versus initial junction temperature (sinusoidal waveform)**



## 2.0 TO-220 ins. package information

Figure 12. TO-220 ins. package outline



**Table 6. T0-220 ins. package mechanical data**

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
B	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
C	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
e	4.80		5.40	0.189		0.212
F	6.20		6.60	0.244		0.259
Øl	3.75		3.85	0.147		0.151
I4	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
I2	1.14		1.70	0.044		0.066
M		2.60			0.102	

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